

DS26C31T/DS26C31M

CMOS Quad TRI-STATE® Differential Line Driver

General Description

The DS26C31 is a quad differential line driver designed for digital data transmission over balanced lines. The DS26C31T meets all the requirements of EIA standard RS-422 while retaining the low power characteristics of CMOS. The DS26C31M is compatible with EIA standard RS-422; however, one exception in test methodology is taken (Note 8). This enables the construction of serial and terminal interfaces while maintaining minimal power consumption.

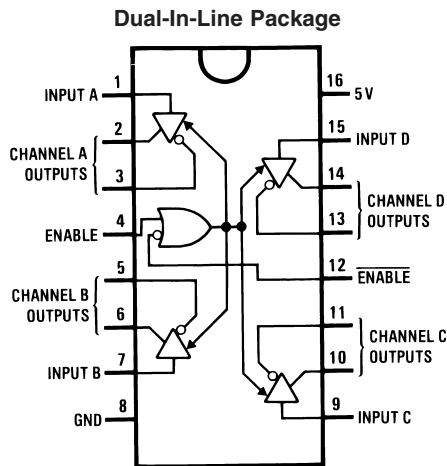
The DS26C31 accepts TTL or CMOS input levels and translates these to RS-422 output levels. This part uses special output circuitry that enables the drivers to power down without loading down the bus. This device has enable and disable circuitry common to all four drivers. The DS26C31 is pin compatible to the AM26LS31 and the DS26LS31.

All inputs are protected against damage due to electrostatic discharge by diodes to V_{CC} and ground.

Features

- TTL input compatible
- Typical propagation delays: 6 ns
- Typical output skew: 0.5 ns
- Outputs will not load line when $V_{CC} = 0V$
- DS26C31T meets the requirements of EIA standard RS-422
- Operation from single 5V supply
- TRI-STATE outputs for connection to system buses
- Low quiescent current
- Available in surface mount
- Mil-Std-883C compliant

Connection Diagrams

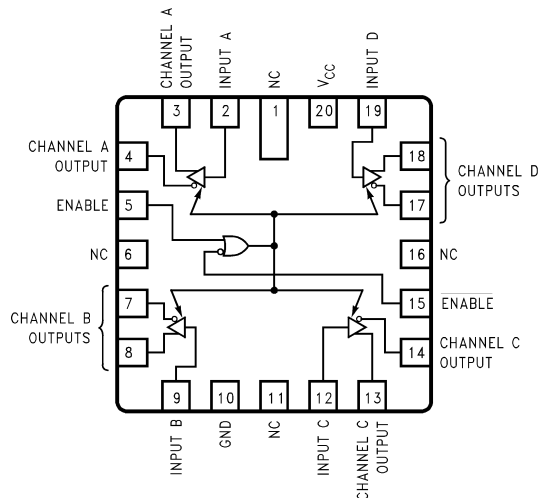


Top View

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Order Number DS26C31TM or DS26C31TN
 See NS Package Number M16A or N16E
 For Complete Military Product Specifications,
 refer to the appropriate SMD or MDS.
 Order Number DS26C31ME/883, DS26C31MJ/883
 or DS26C31MW/883
 See NS Package Number E20A, J16A or W16A

20-Lead Ceramic Leadless Chip Carrier (E)



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Truth Table

ENABLE	ENABLE	Input	Non-Inverting Output	Inverting Output
L	H	X	Z	Z
All other combinations of enable inputs		L	L	H
		H	H	L

L = Low logic state
 X = Irrelevant
 H = High logic state
 Z = TRI-STATE (high impedance)

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Absolute Maximum Ratings (Notes 1,

2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.5V to 7.0V
DC Input Voltage (V_{IN})	-1.5V to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	-0.5V to 7V
Clamp Diode Current (I_{IK}, I_{OK})	± 20 mA
DC Output Current, per pin (I_{OUT})	± 150 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 150 mA
Storage Temperature Range (T_{STG})	-65°C to +150°C
Max. Power Dissipation (P_D) @25°C (Note 3)	
Ceramic "J" Pkg.	2419 mW
Plastic "N" Pkg.	1736 mW

SOIC "M" Pkg.	1226 mW
Ceramic "W" Pkg.	1182 mW
Ceramic "E" Pkg.	2134 mW

Lead Temperature (T_L) (Soldering, 4 sec.) 260°C
This device does not meet 2000V ESD Rating. (Note 13)

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.50	5.50	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)			
DS26C31T	-40	+85	°C
DS26C31M	-55	+125	°C
Input Rise or Fall Times (t_r, t_f)		500	ns

DC Electrical Characteristics

$V_{CC} = 5V \pm 10\%$ (unless otherwise specified) (Note 4)

Symbol	Parameter	Conditions	Min	Typ	Max	Units	
V_{IH}	High Level Input Voltage		2.0			V	
V_{IL}	Low Level Input Voltage				0.8	V	
V_{OH}	High Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} , $I_{OUT} = -20$ mA	2.5	3.4		V	
V_{OL}	Low Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} , $I_{OUT} = 20$ mA		0.3	0.5	V	
V_T	Differential Output Voltage	$R_L = 100\Omega$ (Note 5)	2.0	3.1		V	
$ V_T - \overline{V_T} $	Difference In Differential Output	$R_L = 100\Omega$ (Note 5)			0.4	V	
V_{OS}	Common Mode Output Voltage	$R_L = 100\Omega$ (Note 5)		1.8	3.0	V	
$ V_{OS} - \overline{V_{OS}} $	Difference In Common Mode Output	$R_L = 100\Omega$ (Note 5)			0.4	V	
I_{IN}	Input Current	$V_{IN} = V_{CC}, GND, V_{IH},$ or V_{IL}			± 1.0	μA	
I_{CC}	Quiescent Supply Current (Note 6)	DS26C31T	$V_{IN} = V_{CC}$ or GND		200	500	μA
			$V_{IN} = 2.4V$ or 0.5V (Note 6)		0.8	2.0	mA
		DS26C31M	$V_{IN} = V_{CC}$ or GND		200	500	μA
			$V_{IN} = 2.4V$ or 0.5V (Note 6)		0.8	2.1	mA
I_{OZ}	TRI-STATE Output Leakage Current	$V_{OUT} = V_{CC}$ or GND $\overline{ENABLE} = V_{IL}$ $\overline{ENABLE} = V_{IH}$		± 0.5	± 5.0	μA	
I_{SC}	Output Short Circuit Current	$V_{IN} = V_{CC}$ or GND (Notes 5, 7)	-30		-150	mA	
I_{OFF}	Output Leakage Current Power Off (Note 5)	DS26C31T	$V_{OUT} = 6V$			100	μA
			$V_{OUT} = -0.25V$			-100	μA
		DS26C31M	$V_{OUT} = 6V$			100	μA
			$V_{OUT} = 0V$ (Note 8)			-100	μA

DC Electrical Characteristics (Continued)

Note 1: Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The table of "Electrical Characteristics" provide conditions for actual device operation.

Note 2: Unless otherwise specified, all voltages are referenced to ground. All currents into device pins are positive, all currents out of device pins are negative.

Note 3: Ratings apply to ambient temperature at 25°C. Above this temperature derate N package at 13.89 mW/°C, J package 16.13 mW/°C, M package 9.80 mW/°C, E package 12.20 mW/°C, and W package 6.75 mW/°C.

Note 4: Unless otherwise specified, min/max limits apply across the recommended operating temperature range. All typicals are given for $V_{CC} = 5V$ and $T_A = 25^\circ C$.

Note 5: See EIA Specification RS-422 for exact test conditions.

Note 6: Measured per input. All other inputs at V_{CC} or GND.

Note 7: This is the current sourced when a high output is shorted to ground. Only one output at a time should be shorted.

Note 8: The DS26C31M (-55°C to +125°C) is tested with V_{OUT} between +6V and 0V while RS-422A condition is +6V and -0.25V.

Switching Characteristics

$V_{CC} = 5V \pm 10\%$, $t_r \leq 6$ ns, $t_f \leq 6$ ns (Figures 1, 2, 3, 4) (Note 4)

Symbol	Parameter	Conditions	Min	Typ	Max		Units
					DS26C31T	CS26C31M	
t_{PLH}, t_{PHL}	Propagation Delays Input to Output	S1 Open	2	6	11	14	ns
Skew	(Note 9)	S1 Open		0.5	2.0	3.0	ns
t_{TLH}, t_{THL}	Differential Output Rise And Fall Times	S1 Open		6	10	14	ns
t_{PZH}	Output Enable Time	S1 Closed		11	19	22	ns
t_{PZL}	Output Enable Time	S1 Closed		13	21	28	ns
t_{PHZ}	Output Disable Time (Note 10)	S1 Closed		5	9	12	ns
t_{PLZ}	Output Disable Time (Note 10)	S1 Closed		7	11	14	ns
C_{PD}	Power Dissipation Capacitance (Note 11)			50			pF
C_{IN}	Input Capacitance			6			pF

Note 9: Skew is defined as the difference in propagation delays between complementary outputs at the 50% point.

Note 10: Output disable time is the delay from ENABLE or \overline{ENABLE} being switched to the output transistors turning off. The actual disable times are less than indicated due to the delay added by the RC time constant of the load.

Note 11: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Comparison Table of Switching Characteristics into "LS-Type" Load

$V_{CC} = 5V$, $T_A = 25^\circ C$, $t_r \leq 6$ ns, $t_f \leq 6$ ns (Figures 2, 4, 5, 6) (Note 12)

Symbol	Parameter	Conditions	DS26C31T		DS26LS31C		Units
			Typ	Max	Typ	Max	
t_{PLH}, t_{PHL}	Propagation Delays Input to Output	$C_L = 30$ pF S1 Closed S2 Closed	6	8	10	15	ns
Skew	(Note 9)	$C_L = 30$ pF S1 Closed S2 Closed	0.5	1.0	2.0	6.0	ns
t_{THL}, t_{TLH}	Differential Output Rise and Fall Times	$C_L = 30$ pF S1 Closed S2 Closed	4	6			ns
t_{PLZ}	Output Disable Time (Note 10)	$C_L = 10$ pF S1 Closed S2 Open	6	9	15	35	ns

Comparison Table of Switching Characteristics into “LS-Type”

Load (Continued)

$V_{CC} = 5V$, $T_A = 25^\circ C$, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$ (Figures 2, 4, 5, 6) (Note 12)

Symbol	Parameter	Conditions	DS26C31T		DS26LS31C		Units
			Typ	Max	Typ	Max	
t_{PHZ}	Output Disable Time (Note 10)	$C_L = 10 \text{ pF}$ S1 Open S2 Closed	4	7	15	25	ns
t_{PZL}	Output Enable Time	$C_L = 30 \text{ pF}$ S1 Closed S2 Open	14	20	20	30	ns
t_{PZH}	Output Enable Time	$C_L = 30 \text{ pF}$ S1 Open S2 Closed	11	17	20	30	ns

Note 12: This table is provided for comparison purposes only. The values in this table for the DS26C31 reflect the performance of the device but are not tested or guaranteed.

Note 13: ESD Rating:

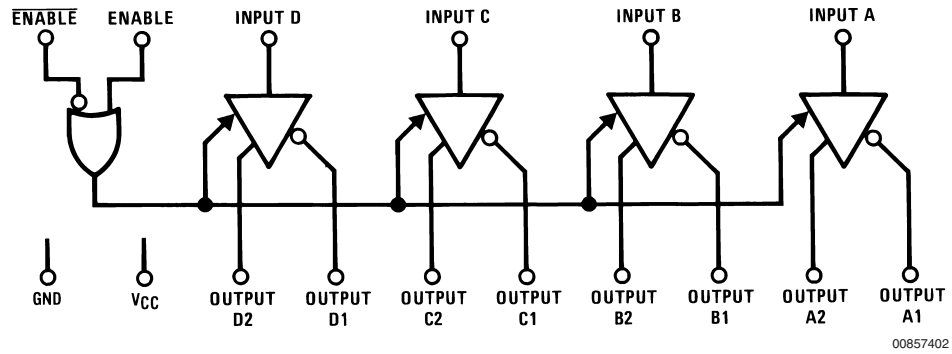
HBM (1.5 k Ω , 100 pF)

Inputs $\geq 1500V$

Outputs $\geq 1000V$

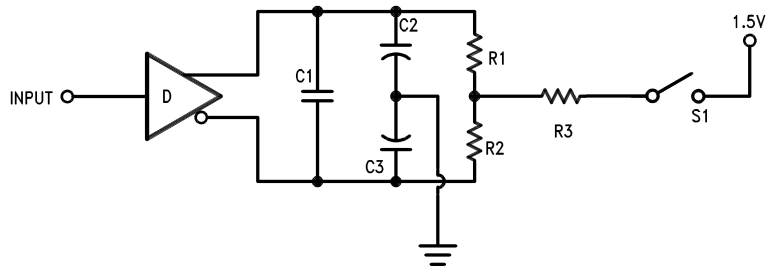
EIAJ (0 Ω , 200 pF) $\geq 350V$

Logic Diagram



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AC Test Circuit and Switching Time Waveforms



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Note: $C1 = C2 = C3 = 40 \text{ pF}$ (Including Probe and Jig Capacitance), $R1 = R2 = 50\Omega$, $R3 = 500\Omega$.

FIGURE 1. AC Test Circuit

AC Test Circuit and Switching Time Waveforms (Continued)

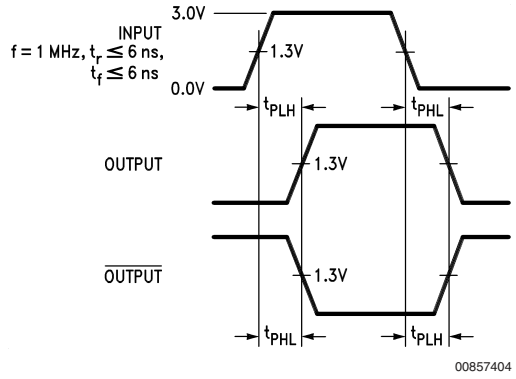


FIGURE 2. Propagation Delays

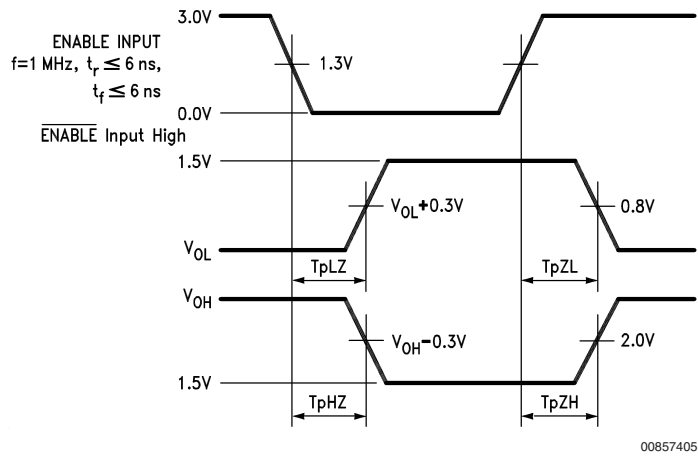
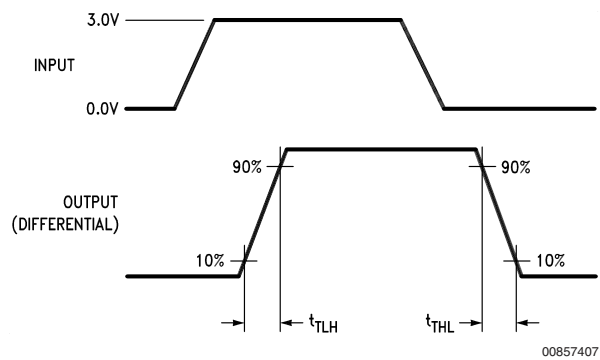


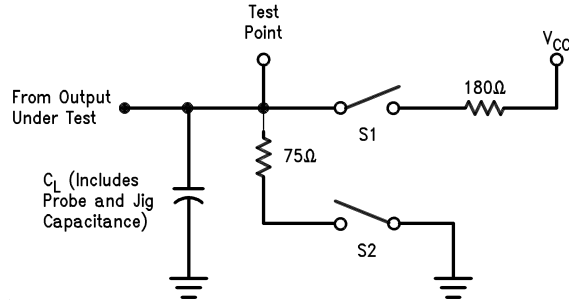
FIGURE 3. Enable and Disable Times



Input pulse; $f = 1 \text{ MHz}$, 50%; $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$

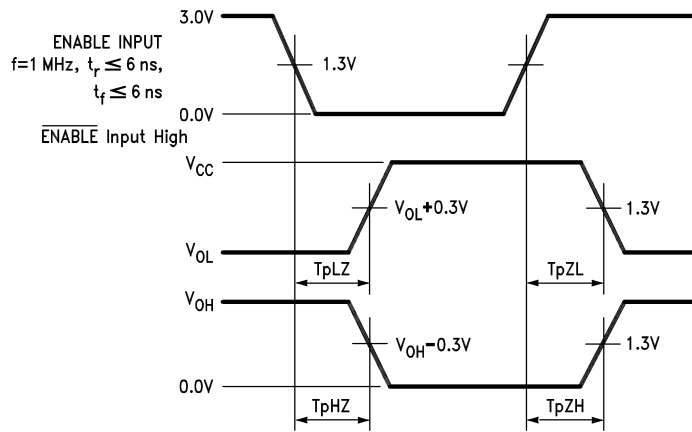
FIGURE 4. Differential Rise and Fall Times

AC Test Circuit and Switching Time Waveforms (Continued)



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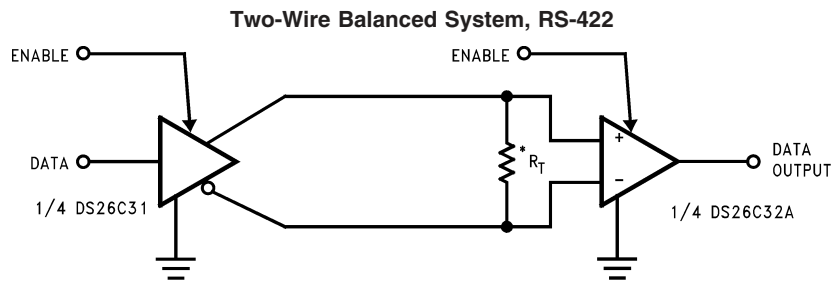
FIGURE 5. Load AC Test Circuit for "LS-Type" Load



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FIGURE 6. Enable and Disable Times for "LS-Type" Load

Typical Applications

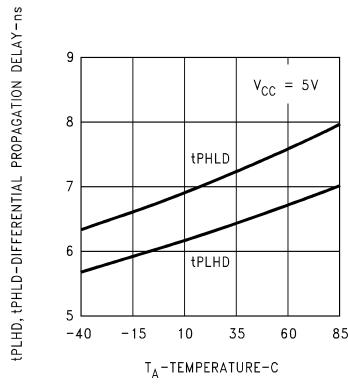


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*RT is optional although highly recommended to reduce reflection.

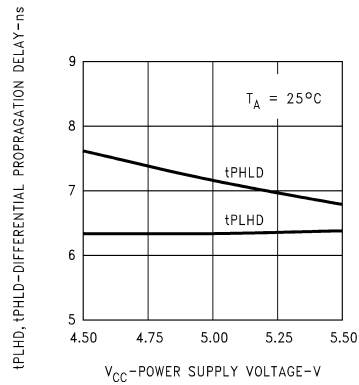
Typical Performance Characteristics

Differential Propagation Delay vs Temperature



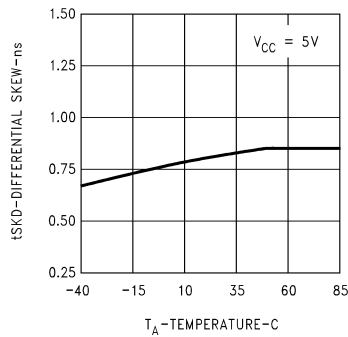
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Differential Propagation Delay vs Power Supply Voltage



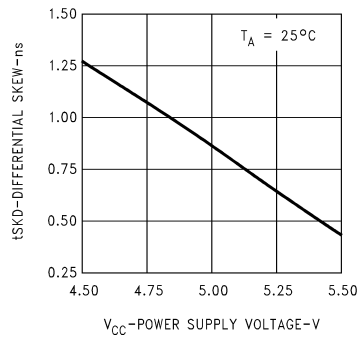
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Differential Skew vs Temperature



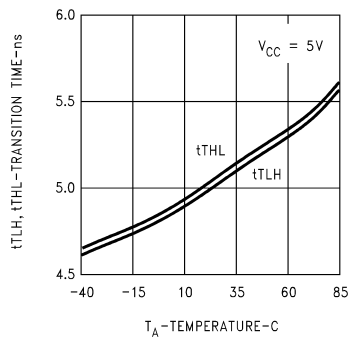
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Differential Skew vs Power Supply Voltage



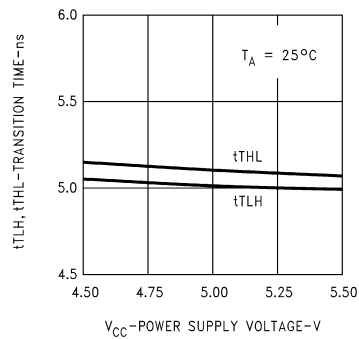
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Differential Transition Time vs Temperature



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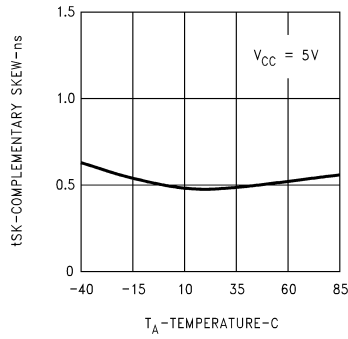
Differential Transition Time vs Power Supply Voltage



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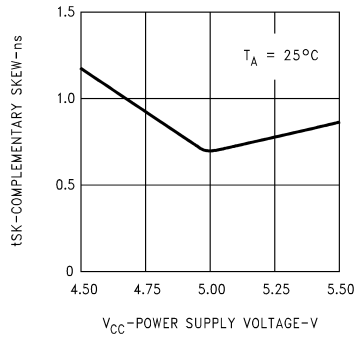
Typical Performance Characteristics (Continued)

Complementary Skew vs Temperature



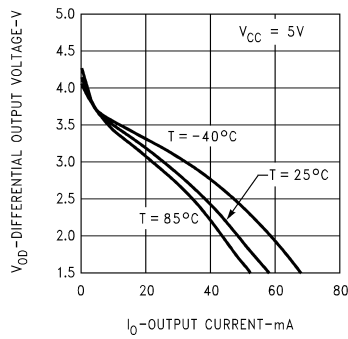
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Complementary Skew vs Power Supply Voltage



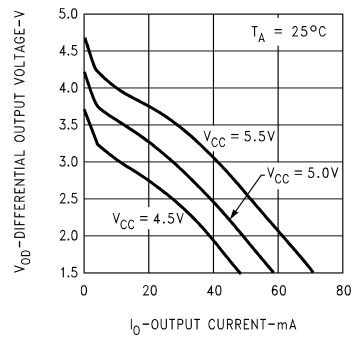
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Differential Output Voltage vs Output Current



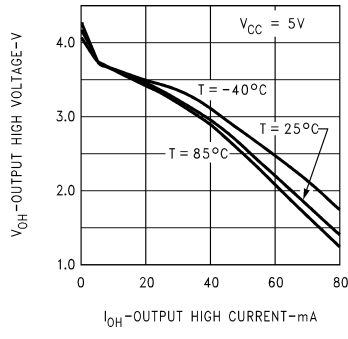
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Differential Output Voltage vs Output Current



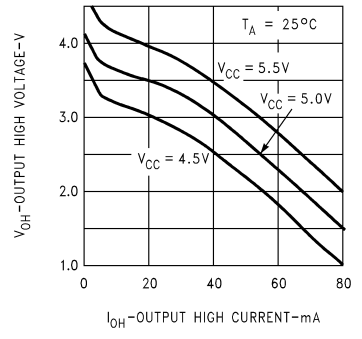
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Output High Voltage vs Output High Current



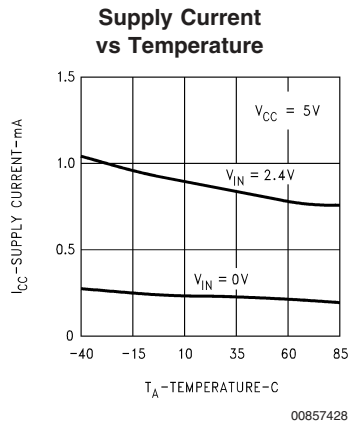
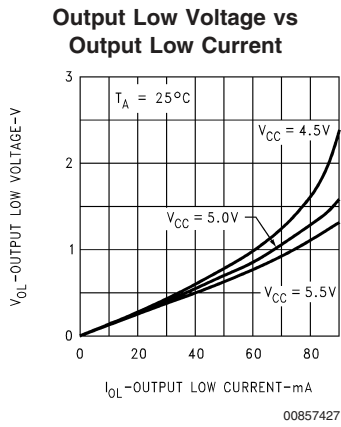
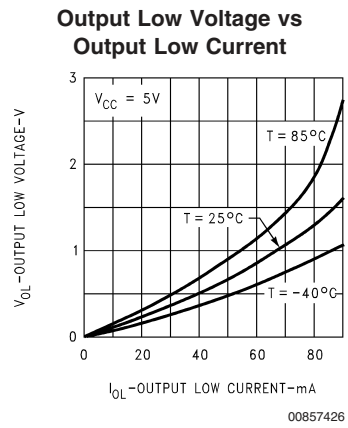
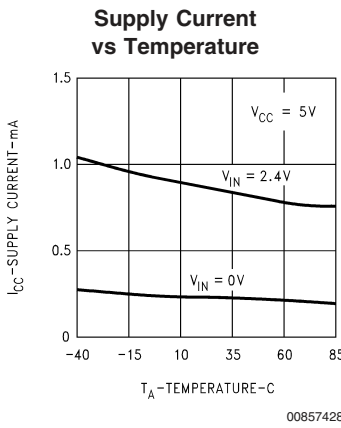
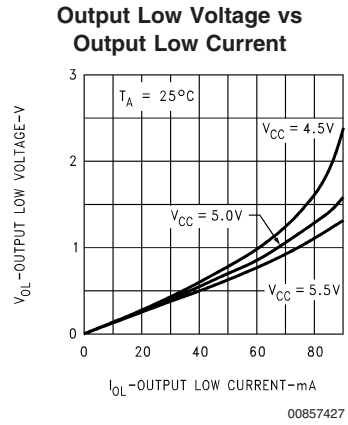
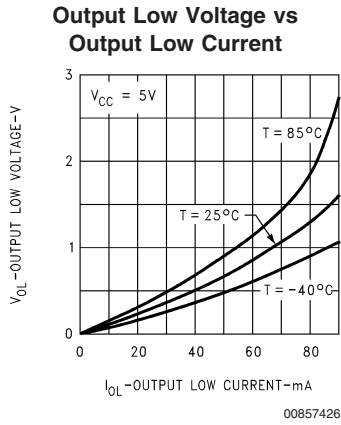
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Output High Voltage vs Output High Current



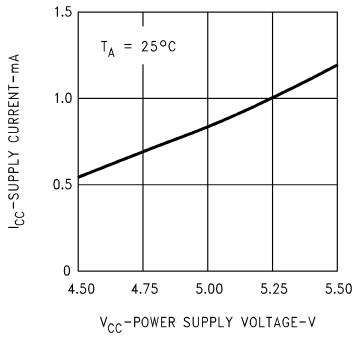
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Typical Performance Characteristics (Continued)



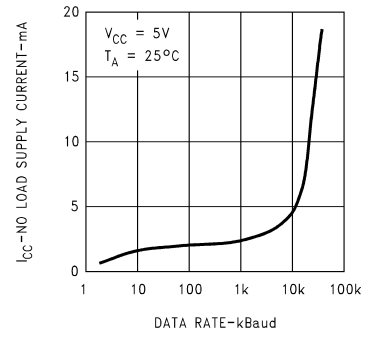
Typical Performance Characteristics (Continued)

Supply Current vs Power Supply Voltage



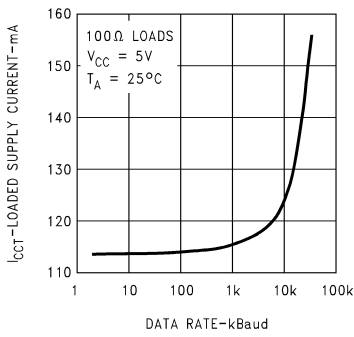
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No Load Supply Current vs Data Rate



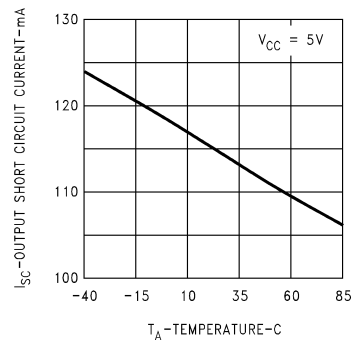
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Loaded Supply Current vs Data Rate



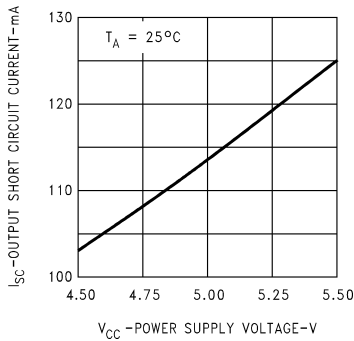
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Output Short Circuit Current vs Temperature



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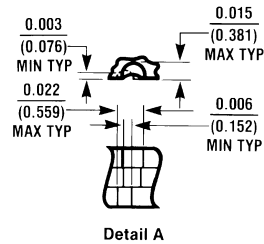
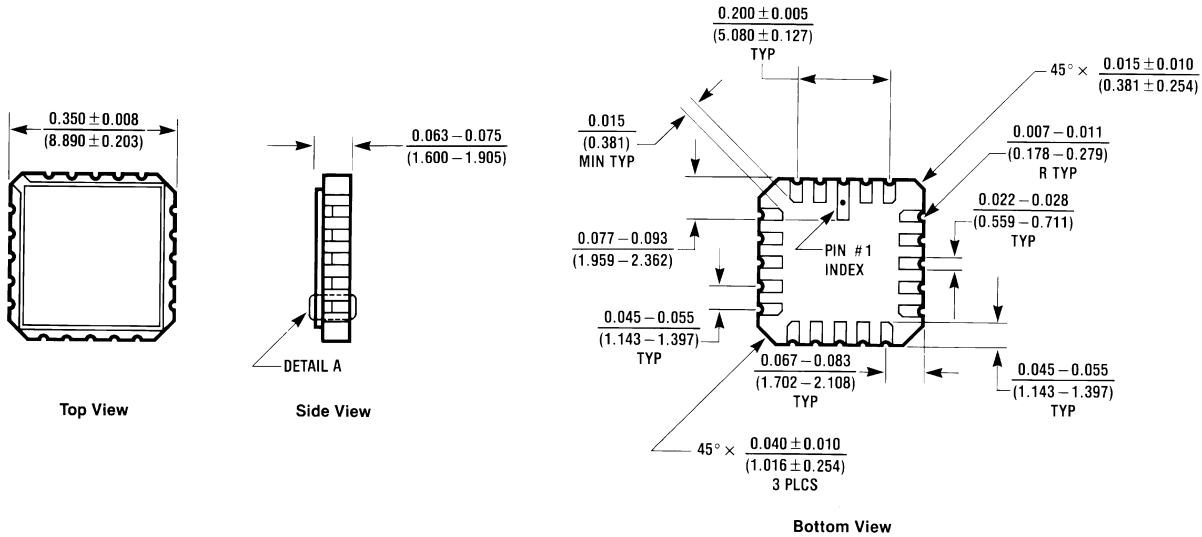
Output Short Circuit Current vs Power Supply Voltage



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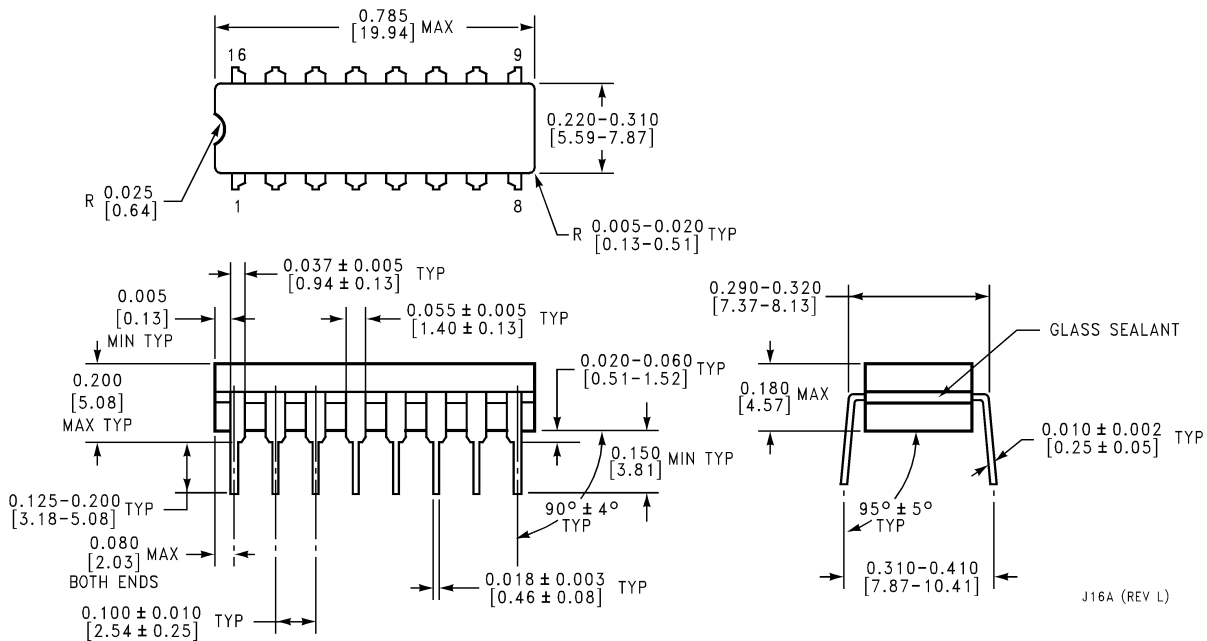
Physical Dimensions inches (millimeters)

unless otherwise noted



E20A (REV D)

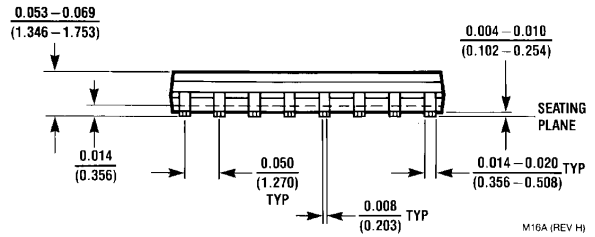
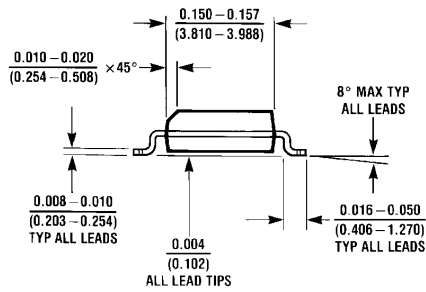
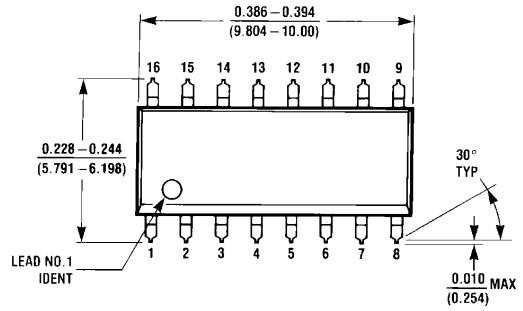
20-Lead Ceramic Leadless Chip Carrier (E)
Order Number DS26C31ME/883
NS Package Number E20A



J16A (REV L)

16-Lead Ceramic Dual-In-Line Package (J)
Order Number DS26C31MJ/883
NS Package Number J16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

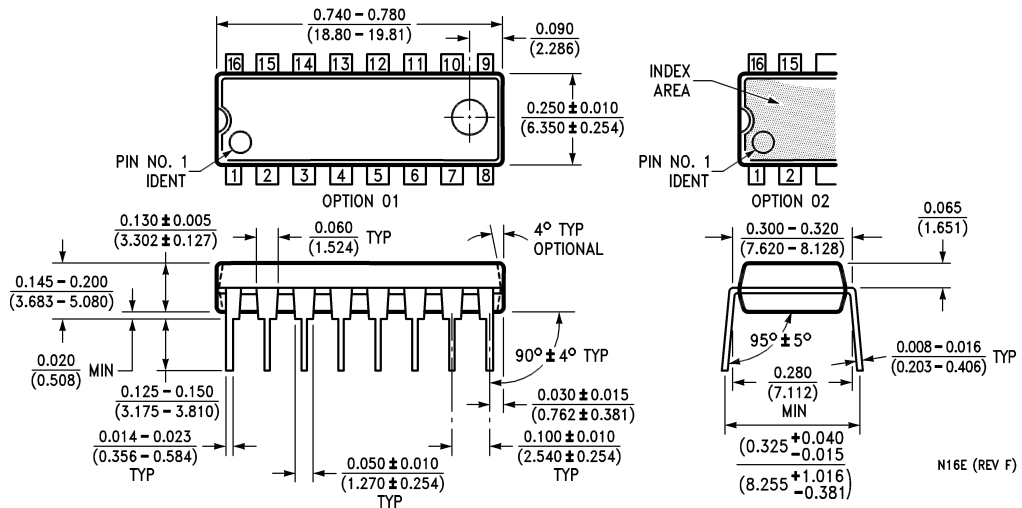


M16A (REV H)

Molded Package Small Outline (M)

Order Number DS26C31TM

NS Package Number M16A



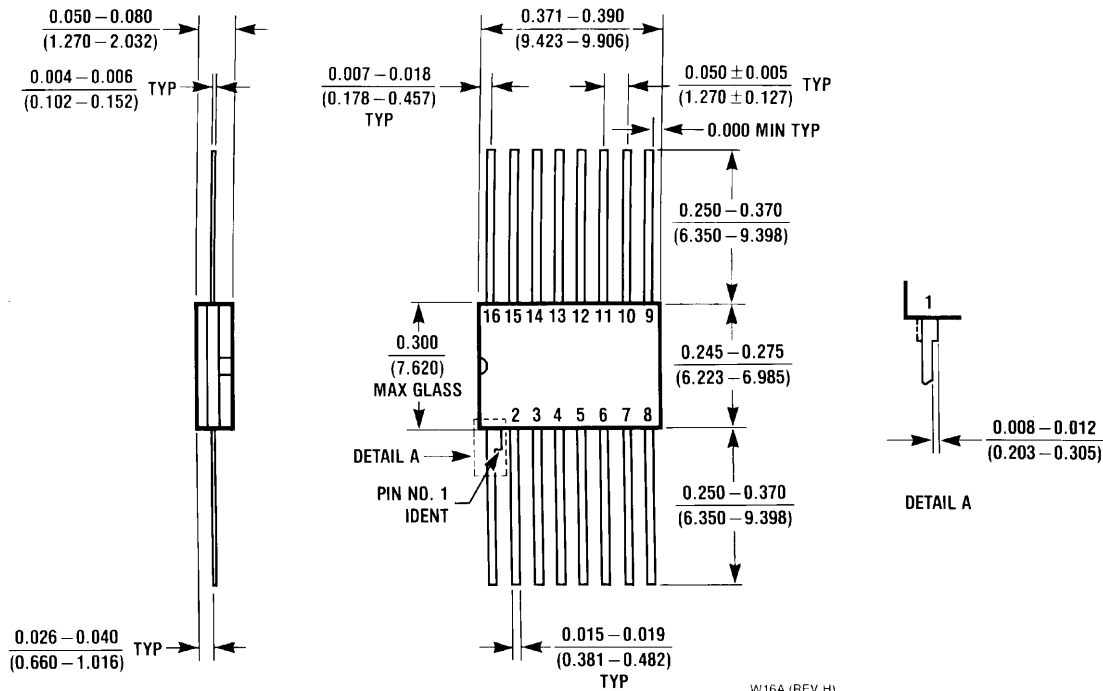
N16E (REV F)

16-Lead Molded Dual-In-Line Package (N)

Order Number DS26C31TN

NS Package Number N16E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Ceramic Flatpak Package (W)
Order Number DS26C31MW/883
NS Package Number W16A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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